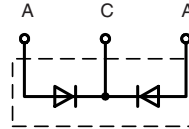


Power Schottky Rectifier with common cathode

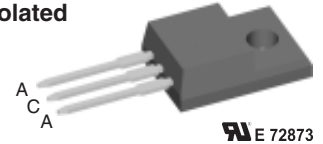
$$\begin{aligned} I_{FAV} &= 2 \times 10 \text{ A} \\ V_{RRM} &= 45 \text{ V} \\ V_F &= 0.56 \text{ V} \end{aligned}$$

Preliminary data

V_{RSM}	V_{RRM}	Type
V	V	
45	45	DSSK 20-0045AM



TO-220 Isolated



Symbol	Conditions	Maximum Ratings	
I_{FRMS}		35	A
I_{FAV}	$T_C = 145^\circ\text{C}$; rectangular, $d = 0.5$	10	A
I_{FAV}	$T_C = 145^\circ\text{C}$; rectangular, $d = 0.5$; per device	20	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t_p = 10 \text{ ms}$ (50 Hz), sine	140	A
E_{AS}	$I_{AS} = 15 \text{ A}$; $L = 100 \mu\text{H}$; $T_{VJ} = 25^\circ\text{C}$; non repetitive	11	mJ
I_{AR}	$V_A = 1.5 \cdot V_{RRM}$ typ.; $f = 10 \text{ kHz}$; repetitive	1.5	A
$(dv/dt)_{cr}$		1000	V/ μs
T_{VJ}		-55...+175	$^\circ\text{C}$
T_{VJM}		175	$^\circ\text{C}$
T_{stg}		-55...+150	$^\circ\text{C}$
P_{tot}	$T_C = 25^\circ\text{C}$	35	W
Weight	typical	2	g

Features

- International standard package
- Very low V_F
- Extremely low switching losses
- Low I_{RM} -values
- Epoxy meets UL 94V-0

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Symbol	Conditions	Characteristic Values	
		typ.	max.
I_R ①	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$; $T_{VJ} = 125^\circ\text{C}$		0.3 mA 2.5 mA
V_F	$I_F = 10 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$ $I_F = 10 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ $I_F = 20 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$		0.56 V 0.69 V 0.69 V
R_{thJC} R_{thCH}	0.5		4.3 K/W K/W

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0%
Data according to IEC 60747 and per diode unless otherwise specified

Dimensions see Outlines.pdf

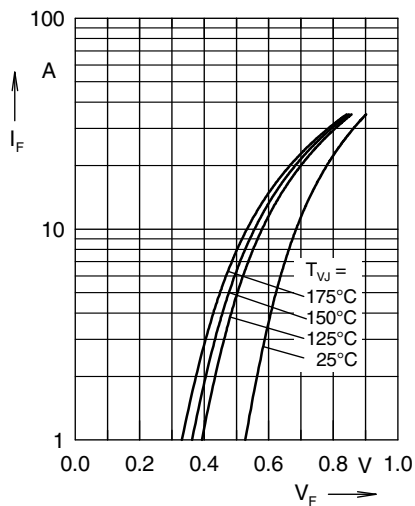


Fig. 1 Maximum forward voltage drop characteristics

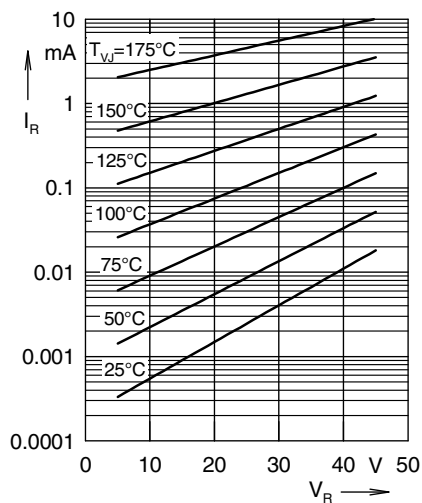


Fig. 2 Typ. value of reverse current I_R versus reverse voltage V_R

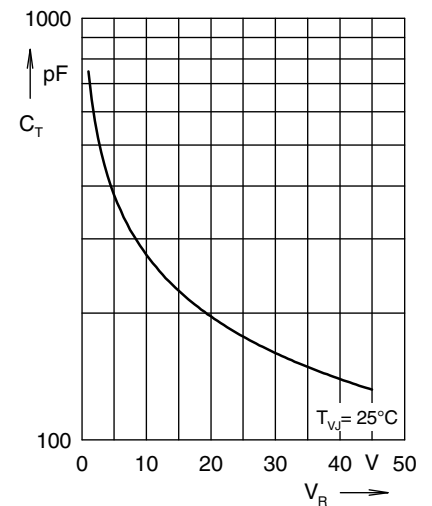
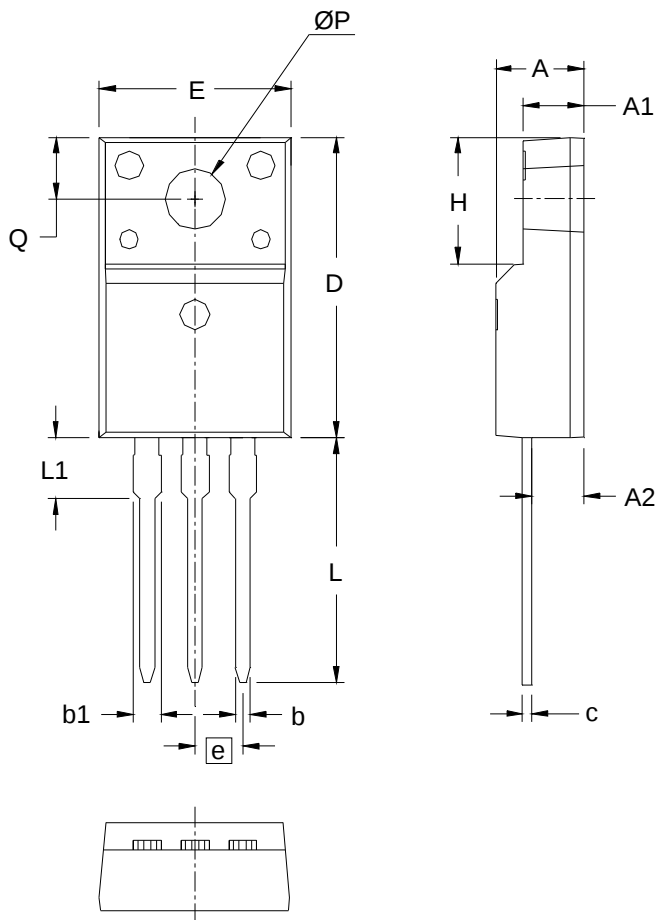


Fig. 3 Typ. junction capacitance C_T versus reverse voltage V_R

Note: All curves are per diode



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.177	.193	4.50	4.90
A1	.092	.108	2.34	2.74
A2	.101	.117	2.56	2.96
b	.028	.035	0.70	0.90
b1	.050	.058	1.27	1.47
c	.018	.024	0.45	0.60
D	.617	.633	15.67	16.07
E	.392	.408	9.96	10.36
e	.100 BSC		2.54 BSC	
H	.255	.271	6.48	6.88
L	.499	.523	12.68	13.28
L1	.119	.135	3.03	3.43
ØP	.121	.129	3.08	3.28
Q	.126	.134	3.20	3.40